Description

The DL0504S3 is an ultra low capacitance TVS array, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive high-speed data lines. The DL0504S3 has an ultra-low capacitance with a typical value at 0.3pF, and complies with the IEC61000-4-2 (ESD) standard with ±15kV air and ±8kV contact discharge. It is assembled into a 6-pin lead-free SOT-363 package. The combination of small size, ultra low capacitance, and high ESD surge capability make it ideal for use in applications such as USB 3.0, multimedia, and other high speed ports.

Features

- Ultra low capacitance: 0.3pF typical（I/O to I/O）
- Ultra low leakage：nA level
- Low clamping voltage
- Operating voltage: 5V
- Up to 4 data lines and one power line protects
- Complies with following standards:
  - IEC 61000-4-2 (ESD) immunity test
    - Air discharge: ±15kV
    - Contact discharge: ±8kV
  - IEC61000-4-5 (Lightning) 5A (8/20μs)
- ROHS Compliant

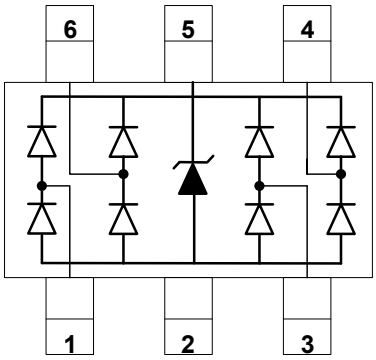
Mechanical Characteristics

- Package: SOT-363
- Lead Finish: Matte Tin
- Case Material: “Green” Molding Compound
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminal Connections: See Diagram Below
- Marking Information: See Below

Applications

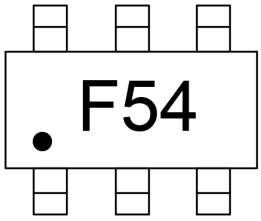
- USB 2.0 and USB 3.0 Ports
- USB OTG
- Digital Visual Interface(DVI)
- Monitor and Flat Panel Displays
- PCI Express and Serial SATA Ports
- Gigabit Ethernet
- IEEE 1394 Firewire Ports
- Consumer products(STB, DVD ,DSC, DVC...)

Dimensions and Pin Configuration



Circuit and Pin Schematic

Marking Information



F54 = Device Marking Code
Dot denotes Pin1

Ordering Information

Part Number	Marking	Packaging	Reel Size
DL0504S3	F54	3000/Tape & Reel	7 inch

Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

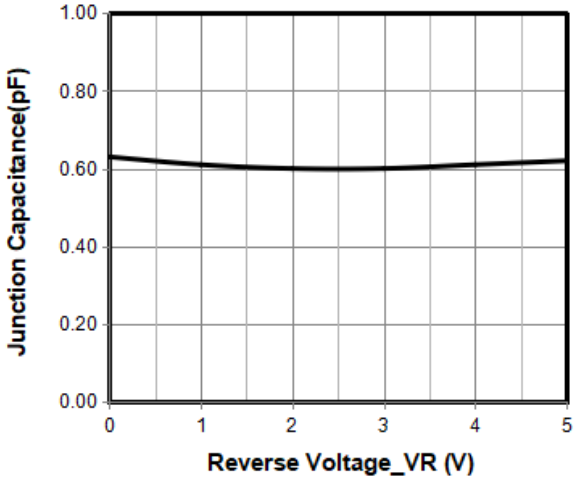
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	Ppk	75	W
Peak Pulse Current (8/20μs)	I_{PP}	5	A
ESD per IEC 61000−4−2 (Air) ESD per IEC 61000−4−2 (Contact)	V_{ESD}	±15 ±8	kV
Operating Temperature Range	T_J	−55 to +125	°C
Storage Temperature Range	Tstg	−55 to +150	°C

Electrical Characteristics (T_A=25°C unless otherwise specified)

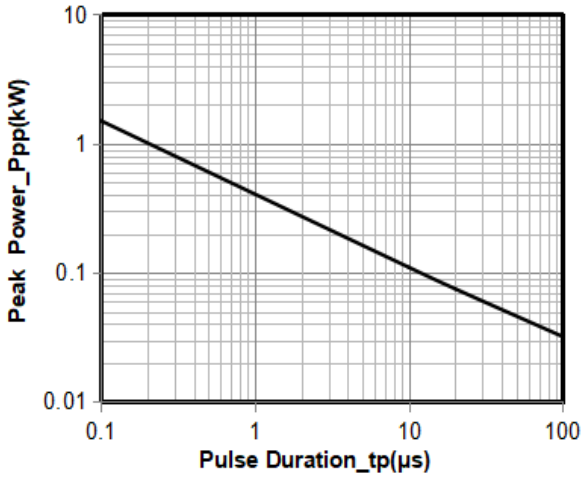
Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V_{RWM}			5	V	Any I/O pin to ground
Breakdown Voltage	V_{BR}	6			V	I_T = 1mA, any I/O pin to ground
Reverse Leakage Current	I_R			0.5	μA	V_{RWM} = 5V, any I/O pin to ground
Clamping Voltage	V_C			10	V	I_{PP} = 1A (8 x 20μs pulse), any I/O pin to ground
Clamping Voltage	V_C			15	V	I_{PP} = 5A (8 x 20μs pulse), any I/O pin to ground
Junction Capacitance	C_J		0.3	0.4	pF	VR = 0V, f = 1MHz, between I/O pins
Junction Capacitance	C_J			0.8	pF	VR = 0V, f = 1MHz, any I/O pin to ground

Note 1: I/O pins are Pin 1, 3, 4 and 6

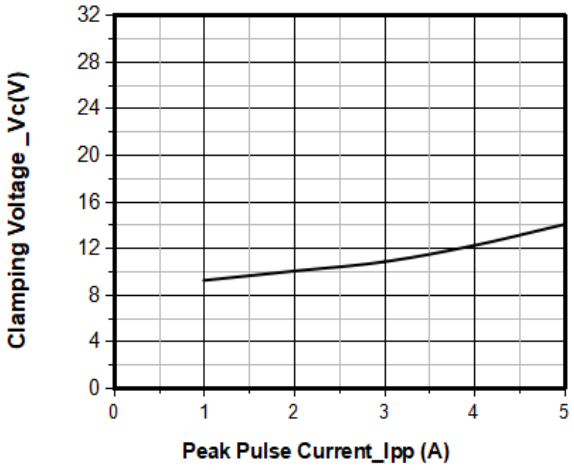
Typical Performance Characteristics (TA=25℃ unless otherwise Specified)



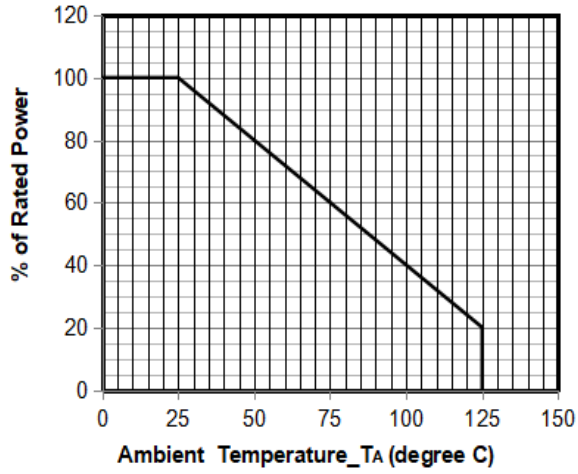
Junction Capacitance vs. Reverse Voltage



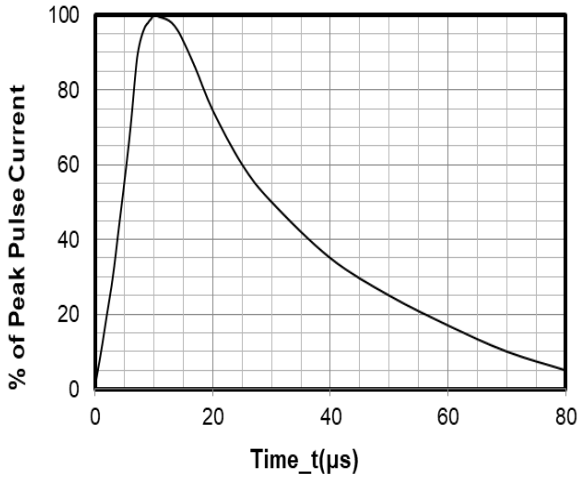
Peak Pulse Power vs. Pulse Time



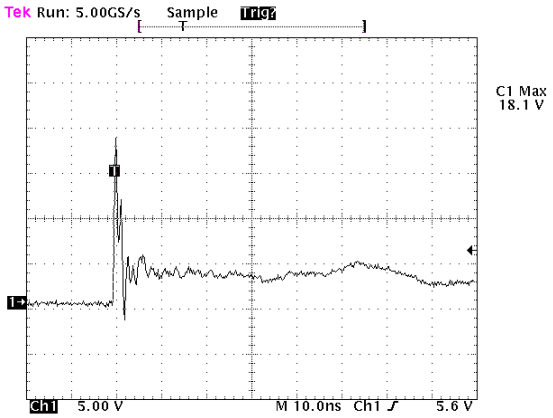
Clamping Voltage vs. Peak Pulse Current



Power Derating Curve



8 X 20μs Pulse Waveform

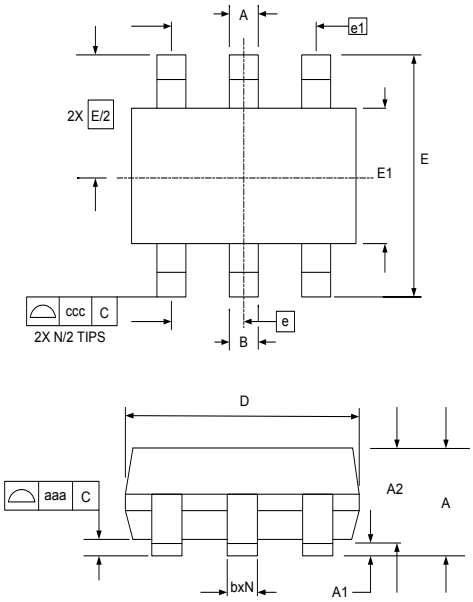


Note：Data is taken with a 10x attenuator

ESD Clamping Voltage

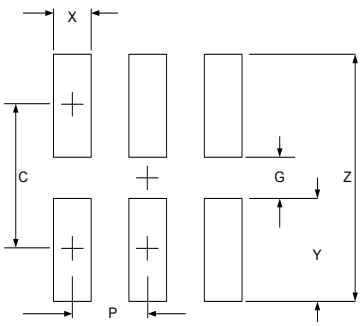
8 kV Contact per IEC61000−4−2

SOT-363 Package Outline Drawing



SYM	DIMENSIONS					
	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A			1.10			0.043
A1	0.00		0.10	0.000		0.004
A2	0.70	0.90	1.00	0.028	0.035	0.039
b	0.15		0.30	0.006		0.012
c	0.08		0.22	0.003		0.009
D	1.80	2.00	2.20	0.071	0.079	0.087
E1	1.15	1.25	1.35	0.045	0.049	0.053
E	2.10 BSC			0.083 BSC		
e	0.65 BSC			0.026 BSC		
e1	1.30 BSC			0.051 BSC		
N	6			6		
aaa	0.10			0.004		
ccc	0.30			0.012		

Suggested Land Pattern



SYM	DIMENSIONS	
	MILLIMETERS	INCHES
C	1.85	0.073
G	1.00	0.039
P	0.65	0.026
X	0.40	0.016
Y	0.85	0.033
Z	2.70	0.106

Contact Information

Changzhou D-first Electronics CO.,Ltd.
www.first-electronic.com
Email: yf@first-electronic.cn
Phone: +86（0519）-8817 1671